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#### United States Patent and Trademark Office



| APPLICATION NO.                             | FILING DATE                            | FIRST NAMED INVENTOR | ATTORNEY DOCKET NO.     | CONFIRMATION NO. |
|---|--|----------------------|-------------------------|------------------|
| 09/652,619                                  | 08/31/2000                             | Gurtej Singh Sandhu  | 303.085US4              | 4342             |
| 21186                                       | 7590 04/26/2002                        |                      |                         |                  |
| SCHWEGMAN, LUNDBERG, WOESSNER & KLUTH, P.A. |  |                      | EXAMINER                |                  |
|   | P.O. BOX 2938<br>MINNEAPOLIS, MN 55402 |                      | BERRY, RENEE R          |                  |
|   |  |                      | ART UNIT                | PAPER NUMBER     |
|   |  |                      | 2818                    |                  |
|   |  |                      | DATE MAILED: 04/26/2002 |                  |

Please find below and/or attached an Office communication concerning this application or proceeding.

Application No. 09/652,619 Applicant(s)

Office Action Summary

Sandhu et al.



| <i>0,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,</i>   | Renee Berry  | Art Unit <b>2818</b>   |  |  |  |
|--|--|--|--|--|--|
| The MAILING DATE of this communication appears   | on the cover sheet with the corres   | pondence addre   | 9SS  |  |  |
| Period for Reply  A SHORTENED STATUTORY PERIOD FOR REPLY IS SET THE MAILING DATE OF THIS COMMUNICATION.  - Extensions of time may be available under the provisions of 37 C after SIX (6) MONTHS from the mailing date of this communic.  - If the period for reply specified above is less than thirty (30) days be considered timely.  - If NO period for reply is specified above, the maximum statutory communication.  - Failure to reply within the set or extended period for reply will, be any reply received by the Office later than three months after the earned patent term adjustment. See 37 CFR 1.704(b). | CFR 1.136 (a). In no event, however, recation.  s, a reply within the statutory minimum period will apply and will expire SIX (6)  y statute, cause the application to bec | may a reply be ting of thirty (30) days.  MONTHS from ome ABANDONE | ays will<br>the mailing date of this<br>D (35 U.S.C. § 133). |  |  |
| Status  1) Responsive to communication(s) filed on   |  |  |  |  |  |
| 2a) ☐ This action is <b>FINAL</b> . 2b) ☑ This ac  | tion is non-final.   |  | _  |  |  |
| 3) Since this application is in condition for allowance closed in accordance with the practice under Ex pa   |  |  | e merits is  |  |  |
| Disposition of Claims  |  |  |  |  |  |
| 4) 💢 Claim(s) <u>21-31 and 55-99</u>   | is/are   | pending in the   | e application.   |  |  |
| 4a) Of the above, claim(s) 55-90   | is/ar  | e withdrawn fr   | om consideration.  |  |  |
| 5) Claim(s)  |  | is/are allowed.  |  |  |  |
| 6) 💢 Claim(s) <u>21-31 and 91-99</u>   |  | is/are rejected  |  |  |  |
| 7) Claim(s)  |  | is/are objected  | l to.  |  |  |
| 8) Claims  | are subject to restric   | tion and/or ele  | ction requirement.   |  |  |
| Application Papers   |  |  |  |  |  |
| 9) The specification is objected to by the Examiner.   |  |  |  |  |  |
| 10) The drawing(s) filed on is/are   | e objected to by the Examiner.   |  |  |  |  |
| ☐ The proposed drawing correction filed on is: a) ☐ approved b) ☐ disapproved.   |  |  |  |  |  |
| 12) The oath or declaration is objected to by the Exam   | niner.   |  |  |  |  |
| Priority under 35 U.S.C. § 119  13) Acknowledgement is made of a claim for foreign p  a) All b) Some* c) None of:  1. Certified copies of the priority documents have  2. Certified copies of the priority documents have  3. Copies of the certified copies of the priority documents have application from the International Bure  *See the attached detailed Office action for a list of the  | ve been received. ve been received in Application N documents have been received in eau (PCT Rule 17.2(a)).  | )<br>O   | ·<br>Stage   |  |  |
| 14) Acknowledgement is made of a claim for domestic  |  | e).  |  |  |  |
| , ,, , tokilowidagomone is made of a diam for domostic   | , p  | <del>-,</del> -  |  |  |  |
| Attachment(s)  |  |  |  |  |  |
| 15) Notice of References Cited (PTO-892)  16) Notice of Draftsperson's Patent Drawing Review (PTO-948)   | 18) Interview Summary (PTO-413) Paper No(s)  19) Notice of Informal Patent Application (PTO-152)   |  |  |  |  |
| 17) Information Disclosure Statement(s) (PTO-1449) Paper No(s).  | 20) Other:   |  |  |  |  |

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#### **DETAILED ACTION**

#### Election/Restriction

- 1. Applicant's election without traverse of Group I in Paper No. 7 is acknowledged.
- 2. Claims 55-90 are withdrawn from further consideration pursuant to 37 CFR 1.142(b) as being drawn to a nonelected invention, there being no allowable generic or linking claim. Election was made without traverse in Paper No. 7.

### Claim Rejections - 35 USC § 103

- 3. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
  - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 4. Claims 21-31 and 91-99 are rejected under 35 U.S.C. 103(a) as being unpatentable over US patent no. 6,369,430 to Adetutu et al. in view of US patent no. 6,143,593 to Augusto.

In regard to claims 21 and 91, Adetutu teaches an integrated circuit having a substrate; a first layer of material formed on the substrate (silicate glass oxide/BPSG), the first layer having contact vias extending through to the substrate; a second layer formed on the first layer, the

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second layer lining the contact vias; and a metallization layer on the second layer at column 3, lines 34-38 and column 4, lines 13-20.

In regard to claims 22 and 26, Adetutu teaches the metallization layer comprises non-alloy copper at column 4, lines 15-18.

In regard to claim 23, Adetutu teaches the metallization layer fills the contact vias.

In regard to claim 24, Augusto teaches the first layer has a first surface potential and the second layer has a second surface potential, and wherein the first surface potential is lower than the second surface potential.

In regard to claim 27, Adetutu teaches the first layer comprises poly-silicon and the second layer comprises titanium nitride at column 2, lines 45-50.

In regard to claim 95, Adetutu teaches the second layer includes titanium nitride at column 4, lines 6-12.

In regard to claim 97, Adetutu teaches the first layer and the second layer have a thickness on the order of 100 to 500 Angstroms at column 3, lines 30-33.

However, Adetutu does not teach the first layer has a first surface voltage, the second layer has a second surface voltage, and the first surface voltage is lower than the second surface voltage.

In regard to claim 25, Augusto teaches an integrated circuit having a substrate; a first layer of material formed on the substrate, the first layer having a first surface voltage; a second layer of material formed on the first layer, the second layer having a second surface voltage, the second

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surface voltage being different than the first surface voltage; and a metallization layer formed on the second layer.

In regard to claim 28, Augusto teaches the first surface voltage is lower than the second surface voltage at column 17, lines 1-22.

In regard to claim 29, Augusto teaches an integrated circuit having a substrate; a first layer of material formed on the substrate; a first layer of formed on the substrate; an insulator layer formed on the first layer, the insulator layer and the first layer having contact vias; a second layer formed on the first layer, the second layer lining the contact vias; and a metallization layer on the second layer at column 17, lines 1-22.

In regard to claim 30, Augusto teaches the metallization layer on the second layer fills the contact vias at column 12, lines 10-16, figure 23, ref # 76.

In regard to claim 31, Augusto teaches the first layer and the second layer have exposed surfaces upon which voltage may be applied at column 17, lines 1-22.

In regard to claim 92, Augusto teaches the first layer of material includes doped polysilicon at column 14, lines 31-35.

In regard to claim 93, Augusto teaches the first layer of material includes undoped polysilicon at column 14, lines 31-35.

In regard to claim 96, Augusto teaches the second layer includes a barrier layer material at column 12, lines 5-11.

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In regard to claim 99, Augusto teaches the first layer has a first surface voltage, the

second layer has a second surface voltage, and the first surface voltage is lower than the second

surface voltage at column 17, lines 1-22.

Therefore, it would have been obvious to one having ordinary skill in the art at the time

the invention was made to have modified Adetutu to include the first layer has a first surface

voltage, the second layer has a second surface voltage, and the first surface voltage is lower than

the second surface voltage, since such a modification would result in an improved charge carrier

mobility of the channel films, as described in column 4, lines 20-25 of Augusto.

Conclusion

Any inquiry concerning this communication or earlier communications from the examiner 5.

should be directed to R. R. Berry whose telephone number is (703) 305-4544.

MALIN

April 22, 2002